

FCC PART 27 TEST REPORT

FCC Part 27

 Report Reference No......
 MWR161000108

 FCC ID......
 RQQHLT-L55UTM

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Date of issue...... October 24, 2016

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Guangdong, China

Testing Laboratory Name Shenzhen CTL Testing Technology Co., Ltd.

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Nanshan, Shenzhen 518055 China

Applicant's name..... HYUNDAI CORPORATION

Address 140-2, Kye-dong, Chongro-ku, Seoul, South Korea

Test specification:

FCC CFR Title 47 Part 2, Part 27

Standard EIA/TIA 603-D: 2010

KDB 971168 D01

TRF Originator...... Maxwell International Co., Ltd.

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Test item description Mobile Phone

Trade Mark HYUNDAI

Manufacturer...... Shenzhen Rainbow Time Technology Co.,Ltd

Model/Type reference...... TITAN LTE

Listed Models N/A

Modulation Type QPSK, 16QAM

Rating DC 3.80V

Hardware version 5101SP S52

Software version V1.0

Result..... PASS

Page 2 of 48 Report No.: MWR161000108

TEST REPORT

Test Report No. :	MWR161000108	October 24, 2016
	ININALIGIOOO LOO	Date of issue

Equipment under Test : Mobile Phone

Model /Type : TITAN LTE

Listed Models : N/A

Applicant : HYUNDAI CORPORATION

Address : 140-2, Kye-dong, Chongro-ku, Seoul, South Korea

Manufacturer : Shenzhen Rainbow Time Technology Co.,Ltd

Address : Room 905, ChangHong Technology Building, Science and

Technology Park, Nanshan District, Shenzhen, China

Test Result:	PASS

The test report merely corresponds to the test sample.

It is not permitted to copy extracts of these test result without the written permission of the test laboratory.

Revison History

Report No.: MWR161000108

Revision	Issue Date	Revisions	Revised By
00	2016-10-24	Initial Issue	Dixon Hao

Report No.: MWR161000108

Contents

<u>2.</u>	SUMMARY	<u> 6</u>
2.1.	General Remarks	6
2.2.	Product Description	6
2.3.	Equipment under Test	7
2.4.	Short description of the Equipment under Test (EUT)	7
2.5.	Internal Identification of AE used during the test	7
2.6.	Normal Accessory setting	7
2.7.	EUT configuration	7
2.8.	Related Submittal(s) / Grant (s)	7
2.9.	Modifications	8
2.10.	General Test Conditions/Configurations	8
<u>3.</u>	TEST ENVIRONMENT	9
3.1.	Address of the test laboratory	9
3.2.	Test Facility	9
3.3.	Environmental conditions	9
3.4.	Test Description	9
3.5.	Equipments Used during the Test	10
<u>1.</u>	TEST CONDITIONS AND RESULTS	11
1.1.	Output Power	11
1.2.	Peak-to-Average Ratio (PAR)	16
1.3.	Occupied Bandwidth and Emission Bandwidth	21
1.4.	Band Edge compliance	26
1.5.	Spurious Emssion on Antenna Port	31
l.6.	Radiated Spurious Emssion	40
1.7.	Frequency Stability	46
<u>5.</u>	TEST SETUP PHOTOS OF THE EUT	48
<u>6.</u>	EXTERNAL PHOTOS OF THE EUT	48
7.	INTERNAL PHOTOS OF THE EUT	48

Page 5 of 48 Report No.: MWR161000108

1. TEST STANDARDS

The tests were performed according to following standards:

<u>FCC Part 27(10-1-12 Edition):</u> MISCELLANEOUS WIRELESS COMMUNICATIONS SERVICES <u>TIA/EIA 603 D June 2010:</u> Land Mobile FM or PM Communications Equipment Measurement and Performance Standards.

47 CFR FCC Part 15 Subpart B: - Unintentional Radiators

FCC Part 2: FREQUENCY ALLOCA-TIONS AND RADIO TREATY MAT-TERS; GENERAL RULES AND REG-ULATIONS

ANSI C63.4:2014: Methods of Measurement of Radio-Noise Emissions from Low-Voltage Electrical and Electronic Equipment in the Range of 9 kHz to 40 GHz

FCCKDB971168D01 Power Meas License Digital Systems

2. SUMMARY

2.1. General Remarks

Date of receipt of test sample	:	September 18, 2016
Testing commenced on	:	September 19, 2016
Testing concluded on	:	October 24, 2016

2.2. Product Description

The **HYUNDAI CORPORATION**'s Model: TITAN LTE or the "EUT" as referred to in this report; more general information as follows, for more details, refer to the user's manual of the EUT.

Name of EUT	Mobile Phone
Model Number	TITAN LTE
	GMSK for GSM/GPRS/EDGE, 8-PSK for EDGE only downlink, QPSK
Modilation Type	for UMTS, QPSK/16QAM for LTE
Antenna Type	Internal
UMTS Operation Frequency Band	Device supported UMTS FDD Band II, FDD Band V
OWITO Operation I requestey band	IEEE 802.11b:2412-2462MHz
	IEEE 802.11g:2412-2462MHz
WLAN FCC Operation frequency	IEEE 802.11n HT20:2412-2462MHz
	IEEE 802.11n HT40:2422-2452MHz
BT FCC Operation frequency	2402MHz-2480MHz
HSDPA Release Version	Release 10
HSUPA Release Version	Release 6
DC-HSUPA Release Version	Not Supported
WCDMA Release Version	R99
WODWA Release Version	IEEE 802.11b: DSSS(CCK,DQPSK,DBPSK)
	IEEE 802.11g: OFDM(64QAM, 16QAM, QPSK, BPSK)
WLAN FCC Modulation Type	IEEE 802.11n HT20: OFDM (64QAM, 16QAM, QPSK,BPSK)
	IEEE 802.11n HT40: OFDM (64QAM, 16QAM, QPSK,BPSK)
BT Modulation Type	GFSK,8DPSK,π/4DQPSK(BT3.0+EDR),GFSK(BLE)
Hardware version	5101SP S52
Software version	V1.0
Android version	Android 5.1
GPS function	Supported
WLAN	Supported 802.11b/802.11g/802.11n
Bluetooth	Supported BT 4.0/BT 3.0+EDR
GSM/EDGE/GPRS	Supported GSM/GPRS/EDGE
GSM/EDGE/GPRS Power Class	GSM850:Power Class 4/ PCS1900:Power Class 1
GSM/EDGE/GPRS Operation	GSM850 :824.2MHz-848.8MHz/PCS1900:1850.2MHz-1909.8MHz
Frequency	G3 V 030 .024.2 V
GSM/EDGE/GPRS Operation	GSM850/PCS1900/GPRS850/GPRS1900/EDGE850/EDGE1900
Frequency Band	G3W030/FG3T900/GFK3030/GFK3T900/EDGE030/EDGET900
GSM Release Version	R99
GPRS/EDGE Multislot Class	GPRS: Multi-slot Class 12
Extreme temp. Tolerance	-30°C to +50°C
Extreme vol. Limits	3.40VDC to 4.20VDC (nominal: 3.80VDC)
GPRS operation mode	Class B

Page 7 of 48 Report No.: MWR161000108

2.3. Equipment under Test

Power supply system utilised

Power supply voltage	:	0	120V / 60 Hz	0	115V / 60Hz
		0	12 V DC	0	24 V DC
		•	Other (specified in blank below)		

DC 3.80V

2.4. Short description of the Equipment under Test (EUT)

2.4.1 General Description

TITAN LTE is subscriber equipment in the WCDMA/GSM system. The HSPA/UMTS frequency band is Band I, Band II and Band V; The GSM/GPRS/EDGE frequency band includes GSM850 and GSM900 and DCS1800 and PCS1900, but only Band II, Band V, GSM850 and PCS1900 bands test data included in this report. The Mobile Phone implements such functions as RF signal receiving/transmitting, HSPA/UMTS and GSM/GPRS/EDGE protocol processing, voice, video MMS service, GPS and WIFI etc. Externally it provides micro SD card interface, earphone port (to provide voice service) and SIM card interface. It also provides Bluetooth module to synchronize data between a PC and the phone, or to use the built-in modem of the phone to access the Internet with a PC, or to exchange data with other Bluetooth devices.

NOTE: Unless otherwise noted in the report, the functional boards installed in the units shall be selected from the below list, but not means all the functional boards listed below shall be installed in one unit.

2.5. Internal Identification of AE used during the test

AE ID*	Description
AE1	Battery
AE2	Charger

AE1

Model: DC500

INPUT: AC180-240V~ 50/60Hz 0.15A

OUTPUT: DC 5.0V 1000mA

2.6. Normal Accessory setting

Fully charged battery was used during the test.

2.7. EUT configuration

The following peripheral devices and interface cables were connected during the measurement:

- supplied by the manufacturer
- O supplied by the lab

0	Power Cable	Length (m):	1
		Shield :	1
		Detachable :	1
0	Multimeter	Manufacturer:	1
		Model No.:	1

2.8. Related Submittal(s) / Grant (s)

This submittal(s) (test report) is intended for **FCC ID: RQQHLT-L55UTM** filing to comply with FCC Part 27, Rules.

^{*}AE ID: is used to identify the test sample in the lab internally.

2.9. Modifications

No modifications were implemented to meet testing criteria.

2.10. General Test Conditions/Configurations

2.10.1 Test Environment

Environment Parameter	Selected Values During Tests			
Relative Humidity	Humidity Ambient			
Temperature	TN	Ambient		
	VL	3.40V		
Voltage	VN	3.80V		
	VH	4.20V		

NOTE: VL=lower extreme test voltage VN=nominal voltage VH=upper extreme test voltage TN=normal temperature

3. TEST ENVIRONMENT

3.1. Address of the test laboratory

Shenzhen CTL Testing Technology Co., Ltd.

Floor 1-A, Baisha Technology Park, No. 3011, Shahexi Road, Nanshan, Shenzhen 518055 China

The sites are constructed in conformance with the requirements of ANSI C63.7, ANSI C63.4 (2003) and CISPR Publication 22.

3.2. Test Facility

The test facility is recognized, certified, or accredited by the following organizations:

FCC-Registration No.: 970318

Shenzhen CTL Testing Technology Co., Ltd. EMC Laboratory has been registered and fully described in a report filed with the (FCC) Federal Communications Commission. The acceptance letter from the FCC is maintained in our files. Registration 970318, December 19, 2013.

3.3. Environmental conditions

During the measurement the environmental conditions were within the listed ranges:

Temperature:	15-35 ° C
Humidity:	30-60 %
Atmospheric pressure:	950-1050mbar

3.4. Test Description

3.4.1 AWS Band (1710-1755MHz pairedwith 2110-2155MHz)

Test Item	FCC Rule No.	Requirements	Verdict			
Effective (Isotropic) Radiated Output Power	§2.1046, §27.50(d)	EIRP ≤ 1W;	Pass			
Peak-Average Ratio	§2.1046, §27.50(d)	Limit≤13dB	Pass			
Modulation Characteristics	§2.1047	Digital modulation	N/A			
Bandwidth	§2.1049	OBW: No limit. EBW: No limit.	Pass			
Band Edges Compliance	§2.1051, §27.53(h)	≤ -13dBm/1%*EBW,in1MHz bands immediately outside and adjacent to The frequency block.	Pass			
Spurious Emission at Antenna Terminals	§2.1051, §27.53(h)	≤ -13dBm/1MHz, from 9kHz to 10 th harmonics but outside authorized operating frequency ranges.	Pass			
Field Strength of Spurious Radiation	§2.1055, §27.54	Within authorized bands of operation/frequency block.	Pass			
Frequency Stability	§2.1053, §27.53(h)	≤ -13dBm/1MHz.	Pass			
NOTE 1: For the verdict, the "N/A" denotes "not applicable", the "N/T" de notes "not tested".						

3.5. Equipments Used during the Test

Test Equipment	Manufacturer	Model No.	Serial No.	Calibration Date	Calibration Due Date
Bilog Antenna	Sunol Sciences Corp.	JB1	A061713	2016/06/02	2017/06/01
EMI Test Receiver	R&S	ESCI	103710	2016/06/02	2017/06/01
Spectrum Analyzer	Agilent	N9030A	MY49430428	2016/05/21	2017/05/20
Controller	EM Electronics	Controller EM 1000	N/A	2016/05/21	2017/05/20
Horn Antenna	SCHWARZBECK	BBHA9170D	BBH A9170179	2016/05/19	2017/05/18
Horn Antenna	Sunol Sciences Corp.	DRH-118	A062013	2016/05/19	2017/05/18
EMC Test Software	R&S	ES-K1	N/A	N/A	N/A
EMC Test Software	Audix	E3	N/A	N/A	N/A
Active Loop Antenna	SCHWARZBECK	FMZB1519	1519-037	2016/05/19	2017/05/18
Amplifier	Agilent	8349B	3008A02306	2016/05/19	2017/05/18
Amplifier	Agilent	8447D	2944A10176	2016/05/19	2017/05/18
Temperature/ Humidity Meter	Gangxing	CTH-608	02	2016/05/20	2017/05/19
High-Pass Filter	K&L	9SH10- 2700/X12750-O/O	N/A	2016/05/20	2017/05/19
High-Pass Filter	K&L	41H10- 1375/U12750-O/O	N/A	2016/05/20	2017/05/19
Coaxial Cables	HUBER+SUHNER	SUCOFLEX 104PEA-10M	10m	2016/06/02	2017/06/01
Coaxial Cables	HUBER+SUHNER	SUCOFLEX 104PEA-3M	3m	2016/06/02	2017/06/01
Coaxial Cables	HUBER+SUHNER	SUCOFLEX 104PEA-3M	3m	2016/06/02	2017/06/01
RF Cable	Megalon	RF-A303	N/A	2016/06/02	2017/06/01
Power Sensor	R&S	NRP-Z4	823.3618.03	2016/06/02	2017/06/01
Power Meter	R&S	NRVS	1020.1809.02	2016/06/02	2017/06/01
System Simulator	R&S	CMW500	A130101034	2016/05/22	2017/05/21

4. TEST CONDITIONS AND RESULTS

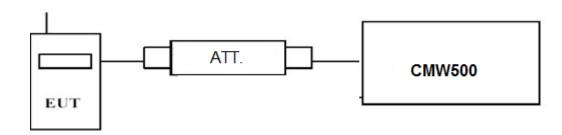
4.1. Output Power

TEST APPLICABLE

During the process of testing, the EUT was controlled via R&S Digital Radio Communication tester (CMW500) to ensure max power transmission and proper modulation. This result contains output power and EIRP measurements for the EUT. In all cases, output power is within the specified limits

4.1.1. Conducted Output Power

TEST CONFIGURATION



TEST PROCEDURE

Conducted Power Measurement:

- a) Place the EUT on a bench and set it in transmitting mode.
- b) Connect a low loss RF cable from the antenna port to a CMW500 by an Att.
- c) EUT Communicate with CMW500 then selects a channel for testing.
- d) Add a correction factor to the display CMW500, and then test.

TEST RESULTS

- We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 7;
- 2. We measured at both SIM 1 and SIM 2, recorded worst case at SIM 1;

		LTE FDD Band 7		
TX Channel	Frequency	DD Cina/Officet	Average Po	ower [dBm]
Bandwidth	(MHz)	RB Size/Offset	QPSK	16QAM
		1 RB low	21.56	20.78
	2502.5	1 RB high	21.41	20.64
	2502.5	50% RB mid	20.56	19.68
		100% RB	20.48	19.57
		1 RB low	21.59	20.86
5 MHz	2535.0	1 RB high	21.53	20.79
SIVITZ	2555.0	50% RB mid	20.58	19.76
		100% RB	20.53	19.60
		1 RB low	21.41	20.59
	2567.5	1 RB high	21.26	20.29
		50% RB mid	20.71	19.78
		100% RB	20.67	19.72
		1 RB low	21.12	20.46
	2505.0	1 RB high	20.43	19.42
	2505.0	50% RB mid	20.32	19.55
		100% RB	20.19	19.42
10 MHz		1 RB low	21.25	20.71
	2525.0	1 RB high	20.13	19.45
	2535.0	50% RB mid	20.24	19.07
		100% RB	20.30	19.58
	2565.0	1 RB low	20.75	20.03

		1 RB high	20.48	19.98
		50% RB mid	20.41	19.45
		100% RB	20.47	19.51
		1 RB low	21.12	20.49
	2507.5	1 RB high	20.68	19.72
	2507.5	50% RB mid	20.19	19.18
		100% RB	20.09	19.01
		1 RB low	21.26	20.64
15 MU-	2525.0	1 RB high	20.74	20.11
15 MHz	2535.0	50% RB mid	20.08	19.06
		100% RB	20.28	19.26
	2562.5	1 RB low	20.26	19.28
		1 RB high	20.52	19.91
		50% RB mid	20.53	19.49
		100% RB	20.22	19.19
	2510.0	1 RB low	20.06	19.18
		1 RB high	20.01	19.11
		50% RB mid	19.87	19.01
		100% RB	19.90	19.06
		1 RB low	21.41	20.98
20 MHz	2525.0	1 RB high	20.87	19.03
ZU IVITZ	2535.0	50% RB mid	19.91	19.06
		100% RB	20.06	19.15
		1 RB low	20.06	19.35
	2560.0	1 RB high	20.45	20.03
	2000.0	50% RB mid	20.56	19.36
		100% RB	19.98	19.23

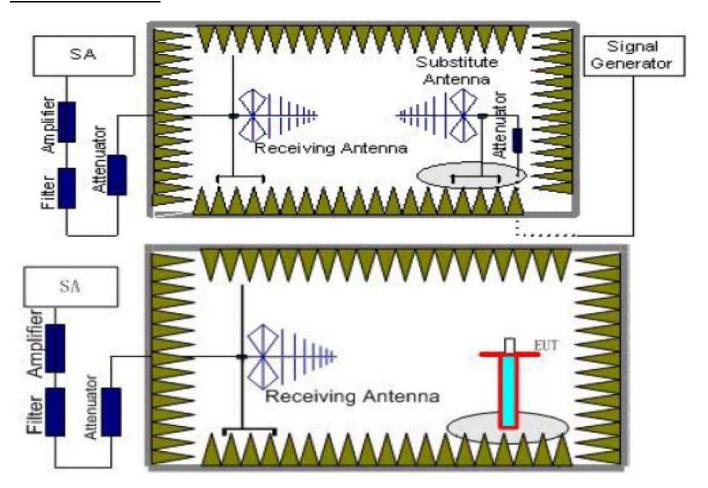
Report No.: MWR161000108

4.1.2. Radiated Output Power

LIMIT

According to §27.50 (d) (4): Fixed, mobile, and portable (hand- held) stations operating in the 1710–1755 MHz band are limited to 1 watt EIRP.

TEST CONFIGURATION



TEST PROCEDURE

- 1. EUT was placed on a 1.50 meter high non-conductive stand at a 3 meter test distance from the receive antenna. A receiving antenna was placed on the antenna mast 3 meters from the EUT for emission measurements. The height of receiving antenna is 1.50m. Detected emissions were maximized at each frequency by rotating the EUT through 360° and adjusting the receiving antenna polarization. The radiated emission measurements of all transmit frequencies in three channels (High, Middle, Low) were measured with peak detector.
- 2. A log-periodic antenna or double-ridged waveguide horn antenna shall be substituted in place of the EUT. The log-periodic antenna will be driven by a signal generator and the level will be adjusted till the same power value on the spectrum analyzer or receiver. The level of the spurious emissions can be calculated through the level of the signal generator, cable loss, the gain of the substitution antenna and the reading of the spectrum analyzer or receiver.
- 3. The EUT is then put into continuously transmitting mode at its maximum power level during the test.Set Test Receiver or Spectrum RBW=1MHz,VBW=3MHz, And the maximum value of the receiver should be recorded as (P_r).
- 4. The EUT shall be replaced by a substitution antenna. In the chamber, an substitution antenna for the frequency band of interest is placed at the reference point of the chamber. An RF Signal source for the frequency band of interest is connected to the substitution antenna with a cable that has been constructed to not interfere with the radiation pattern of the antenna. A power (P_{Mea}) is applied to the input of the substitution antenna, and adjust the level of the signal generator output until the value of the receiver reach the previously recorded (P_r). The power of signal source (P_{Mea}) is recorded. The test should be performed by rotating the test item and adjusting the receiving antenna polarization.

5. A amplifier should be connected to the Signal Source output port. And the cable should be connect between the Amplifier and the Substitution Antenna. The cable loss (P_{cl}) , the Substitution Antenna Gain (G_a) and the Amplifier Gain (P_{Ag}) should be recorded after test.

The measurement results are obtained as described below:

Power(EIRP)= P_{Mea} - P_{Ag} - P_{cl} + G_a

We used SMF100A micowave signal generator which signal level can up to 33dBm,so we not used power Amplifier for substituation test; The measurement results are amend as described below: Power(EIRP)= P_{Mea} - P_{cl} + G_a

- 6. This value is EIRP since the measurement is calibrated using an antenna of known gain (2.15 dBi) and known input power.
- 7. ERP can be calculated from EIRP by subtracting the gain of the dipole, ERP = EIRP-2.15dBi.

TEST RESULTS

Note: We test the H direction and V direction and V direction is worse.

Remark

- 1. We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 4; recorded worst case for each Channel Bandwidth of LTE FDD Band 4.
- 2. $EIRP=P_{Mea}(dBm)-P_{cl}(dB)+P_{Ag}(dB)+G_a(dBi)$
- 3. We measured at SIM 1 as conducted burst average power higher at SIM 1;
- 4. We measured both Horizontal and Vertical direction, recorded worst case direction.

LTE FDD Band 7_Channel Bandwidth 5MHz_QPSK

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	G _a Antenna Gain(dB)	P _{Aq} (dB)	Burst Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
2502.5	-21.89	3.06	9.68	34.8	19.53	30	10.47	V
2535	-21.46	3.17	9.68	34.8	19.85	30	10.15	V
2567.5	-22.73	3.22	9.75	34.8	18.60	30	11.40	V

LTE FDD Band 7 Channel Bandwidth 10MHz QPSK

	_		_		Duret			
Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	G _a Antenna Gain(dB)	P _{Ag} (dB)	Burst Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
2505	-22.69	3.06	9.68	34.8	18.73	30	11.27	V
2535	-21.35	3.17	9.68	34.8	19.96	30	10.04	V
2565	-22.90	3.22	9.75	34.8	18.43	30	11.57	V

LTE FDD Band 7 Channel Bandwidth 15MHz QPSK

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	G _a Antenna Gain(dB)	P _{Aq} (dB)	Burst Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
2507.5	-22.21	3.06	9.68	34.8	19.21	30	10.79	V
2535	-21.25	3.17	9.68	34.8	20.06	30	9.94	V
2562.5	-21.90	3.22	9.75	34.8	19.43	30	10.57	V

LTE FDD Band 7_Channel Bandwidth 20MHz QPSK

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	G _a Antenna Gain(dB)	P _{Aq} (dB)	Burst Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
2510	-22.20	3.06	9.68	34.8	19.22	30	10.78	V
2535	-21.64	3.17	9.68	34.8	19.67	30	10.33	V
2560	-22.64	3.22	9.75	34.8	18.69	30	11.31	V

LTE FDD Band 7_Channel Bandwidth 5MHz_16QAM

	ETET BB Band T_Sharmon Bandwath GWI IE_1047 W									
Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	G _a Antenna Gain(dB)	P _{Ag} (dB)	Burst Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization		
2502.5	-22.47	3.06	9.68	34.8	18.95	30	11.05	V		
2535	-21.97	3.17	9.68	34.8	19.34	30	10.66	V		
2567.5	-23.01	3.22	9.75	34.8	18.32	30	11.68	V		

LTE FDD Band 7_Channel Bandwidth 10MHz_16QAM

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	G _a Antenna Gain(dB)	P _{Ag} (dB)	Burst Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
2505	-22.83	3.06	9.68	34.8	18.59	30	11.41	V
2535	-22.42	3.17	9.68	34.8	18.89	30	11.11	V
2565	-22.62	3.22	9.75	34.8	18.71	30	11.29	V

LTE FDD Band 7_Channel Bandwidth 15MHz_16QAM

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	G _a Antenna Gain(dB)	P _{Aq} (dB)	Burst Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
2507.5	-22.83	3.06	9.68	34.8	18.59	30	11.41	V
2535	-22.47	3.17	9.68	34.8	18.84	30	11.16	V
2562.5	-22.62	3.06	9.68	34.8	18.80	30	11.20	V

LTE FDD Band 7_Channel Bandwidth 20MHz_16QAM

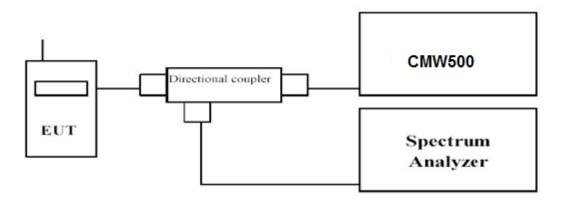
	-		Ga		Burst			
Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Antenna Gain(dB)	P _{Ag} (dB)	Average EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
					(ubiii)			
2510	-22.54	3.06	9.68	34.8	18.88	30	11.12	V
2535	-21.88	3.17	9.68	34.8	19.43	30	10.57	V
2560	-22.45	3.22	9.75	34.8	18.88	30	11.12	V

4.2. Peak-to-Average Ratio (PAR)

<u>LIMIT</u>

The Peak-to-Average Ratio (PAR) of the transmission may not exceed 13 dB.

TEST CONFIGURATION



TEST PROCEDURE

- Refer to instrument's analyzer instruction manual for details on how to use the power statistics/CCDF function:
- 2. Set resolution/measurement bandwidth ≥ signal's occupied bandwidth;
- 3. Set the number of counts to a value that stabilizes the measured CCDF curve;
- 4. Set the measurement interval as follows:
 - 1). for continuous transmissions, set to 1 ms,
 - 2). for burst transmissions, employ an external trigger that is synchronized with the EUT burst timing sequence, or use the internal burst trigger with a trigger level that allows the burst to stabilize and set the measurement interval to a time that is less than or equal to the burst duration.
- 5. Record the maximum PAPR level associated with a probability of 0.1%.

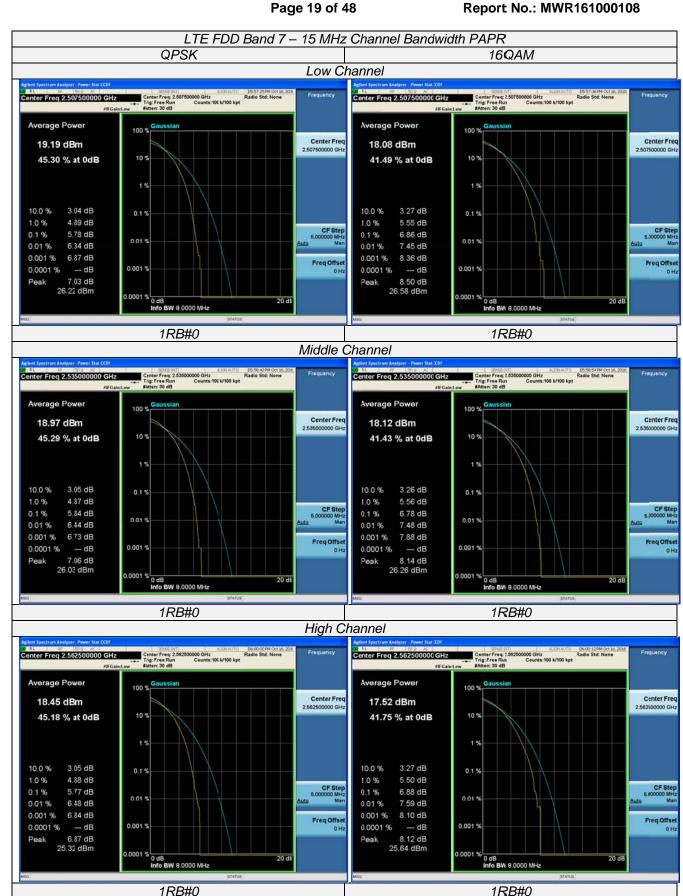
TEST RESULTS

- We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 7; recorded worst case for each Channel Bandwidth of LTE FDD Band 7.
- 2. We measured at SIM 1 as conducted burst average power higher at SIM 1;

		LTE FDD Band 7		
TX Channel	Frequency	RB Size/Offset	PAPI	R (dB)
Bandwidth	(MHz)	RB Size/Offset	QPSK	16QAM
	2502.5		3.50	4.51
5 MHz	2535.0	1RB#0	3.61	4.64
	2567.5		3.88	4.95
	2505.0		5.01	6.00
10 MHz	2535.0	1RB#0	5.15	6.24
	2565.0		5.23	6.20
	2507.5		5.78	6.86
15 MHz	2535.0	1RB#0	5.84	6.78
	2562.5		5.77	6.88
	2510.0		6.46	7.09
20 MHz	2535.0	1RB#0	6.46	7.27
	2560.0		6.44	7.11







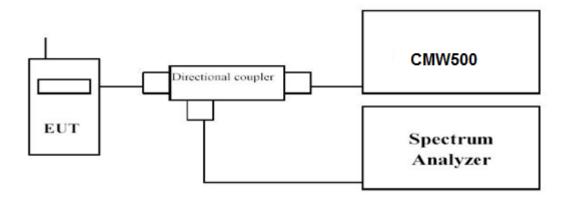


4.3. Occupied Bandwidth and Emission Bandwidth

LIMIT

N/A

TEST CONFIGURATION



TEST PROCEDURE

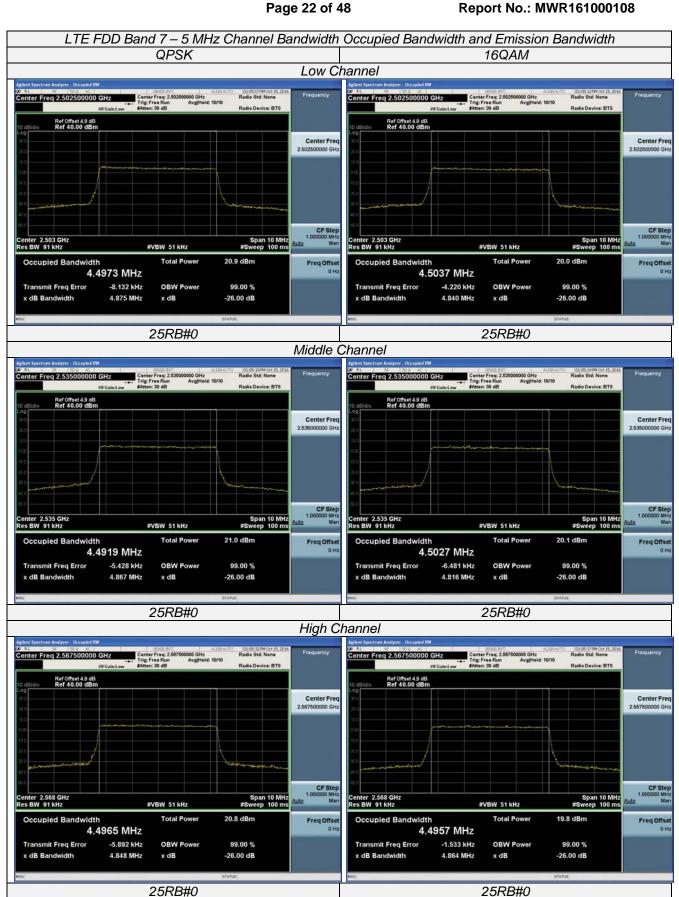
The transmitter output was connected to a calibrated coaxial cable and coupler, the other end of which was connected to a spectrum analyzer. The occupied bandwidth was measured with the spectrum analyzer at low, middle and high channel in each band. The -26dBc Emission bandwidth was also measured and recorded. Set RBW was set to about 1% of emission BW, VBW≥3 times RBW.

-26dBc display line was placed on the screen (or 99% bandwidth), the occupied bandwidth is the delta frequency between the two points where the display line intersects the signal trace.

TEST RESULTS

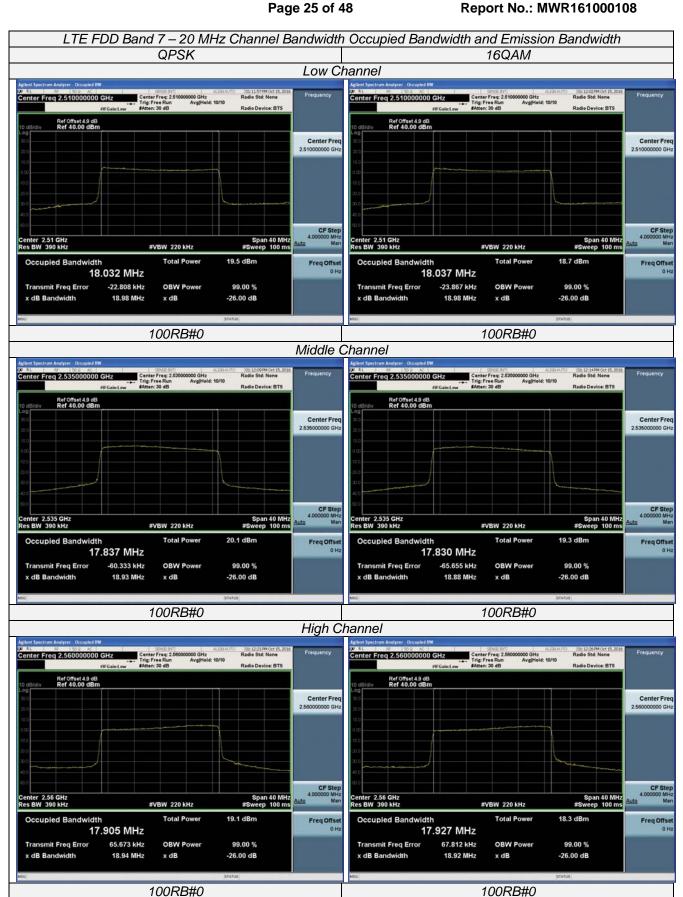
- We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 7; recorded worst case for each Channel Bandwidth of LTE FDD Band 7.
- 2. We measured at SIM 1 as conducted burst average power higher at SIM 1;

LTE FDD Band 7								
TX Channel	RB Size/Offset	Frequency	-26dBc Emission bandwidth (MHz)		99% Occupied bandwidth (MHz)			
Bandwidth		(MHz)	QPSK	16QAM	QPSK	16QAM		
5 MHz	25RB#0	2502.5	4.875	4.840	4.4973	4.5037		
		2535.0	4.867	4.816	4.4919	4.5027		
		2567.5	4.848	4.864	4.4965	4.4957		
10 MHz	50RB#0	2505.0	9.680	9.681	9.0321	9.0385		
		2535.0	9.682	9.660	9.0086	8.9805		
		2565.0	9.690	9.675	8.9932	8.9819		
15 MHz	75RB#0	2507.5	14.18	14.23	13.478	13.476		
		2535.0	14.16	14.18	13.394	13.396		
		2562.5	14.17	14.15	13.409	13.409		
20 MHz	100RB#0	2510.0	18.98	18.98	18.032	18.037		
		2535.0	18.93	18.88	17.937	17.830		
		2560.0	18.94	18.83	17.905	17.927		







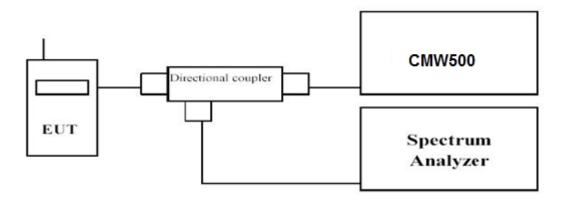


4.4. Band Edge compliance

LIMIT

According to §27.53 (h): For operations in the 1710–1755 MHz and 2110–2155 MHz bands, the power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) by at least 43 + 10 log10(P) dB.

TEST CONFIGURATION

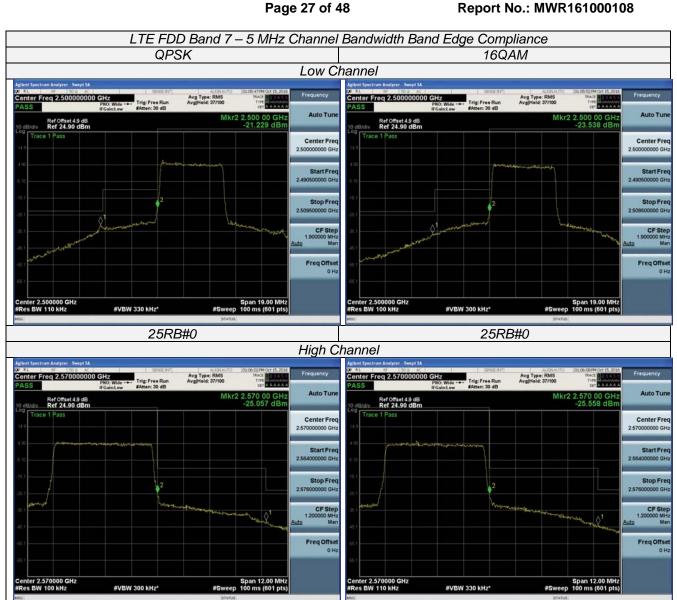


TEST PROCEDURE

- 1. The transmitter output port was connected to base station.
- The RF output of EUT was connected to the power meter by RF cable and attenuator, the path loss was compensated to the results for each measurement.
- 3. Set EUT at maximum power through base station.
- 4. Select lowest and highest channels for each band and different modulation.
- 5. Measure Band edge using RMS (Average) detector by spectrum

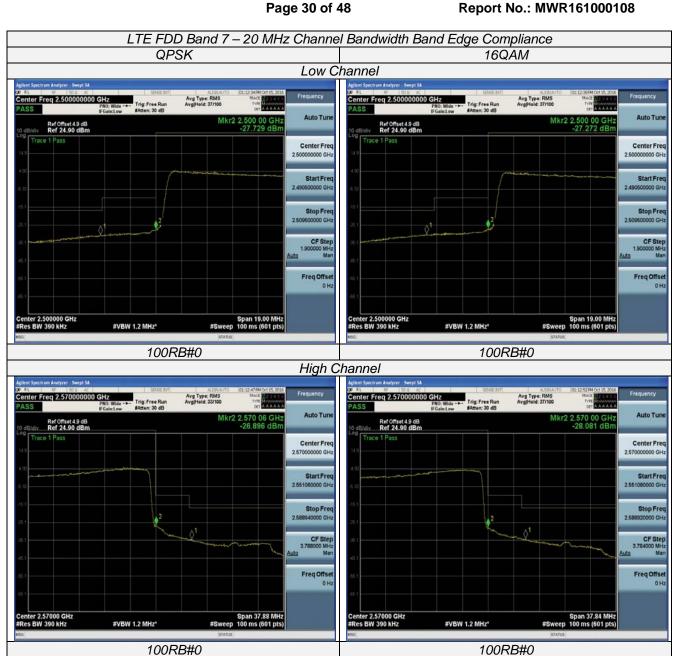
TEST RESULTS

- 1. We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 7; recorded worst case for each Channel Bandwidth of LTE FDD Band 7.
- 2. We measured at SIM 1 as conducted burst average power higher at SIM 1;







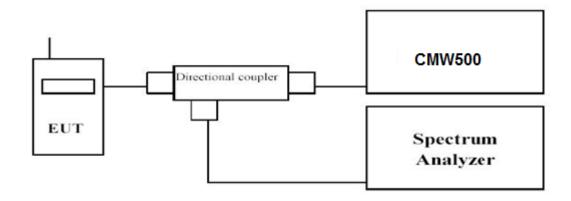


4.5. Spurious Emssion on Antenna Port

<u>LIMIT</u>

According to §27.53 (h): For operations in the 1710–1755 MHz and 2110–2155 MHz bands, the power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) by at least 43 + 10 log10(P) dB.

TEST CONFIGURATION



TEST PROCEDURE

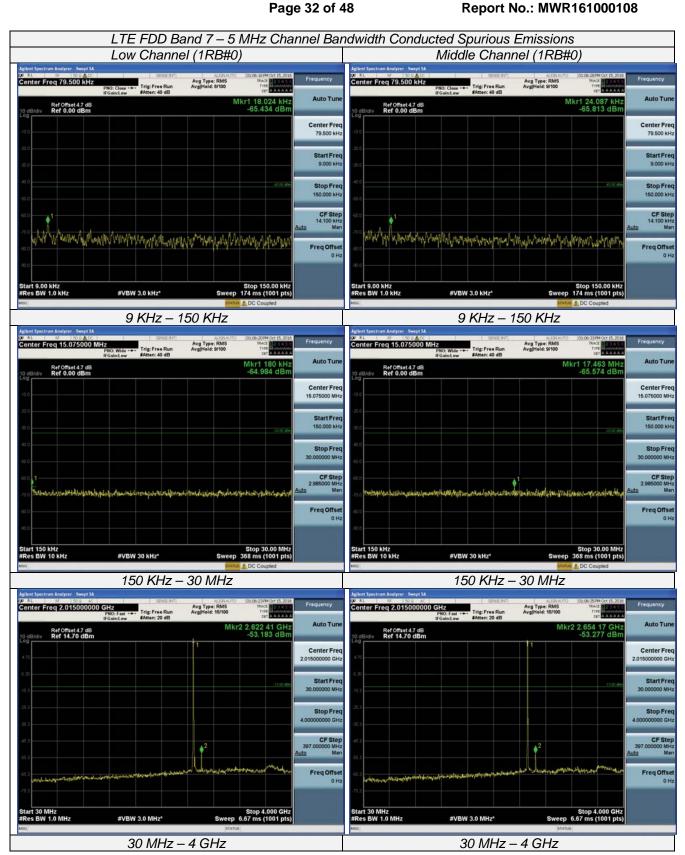
The EUT was setup according to EIA/TIA 603D

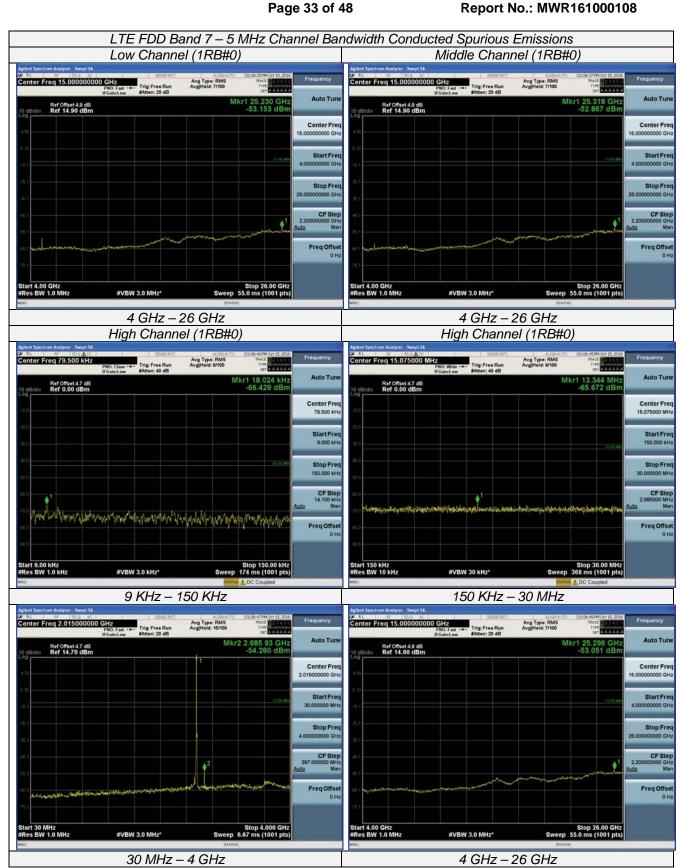
- a. Place the EUT on a bench and set it in transmitting mode.
- b. Connect a low loss RF cable from the antenna port to a spectrum analyzer and CMW500 by a Directional Couple.
- c. EUT Communicate with CMW500, then select a channel for testing.
- d. Add a correction factor to the display of spectrum, and then test.
- e. The resolution bandwidth of the spectrum analyzer was set sufficient scans were taken to show the out of band Emission if any up to10th harmonic.
- f. Please refer to following tables for test antenna conducted emissions.

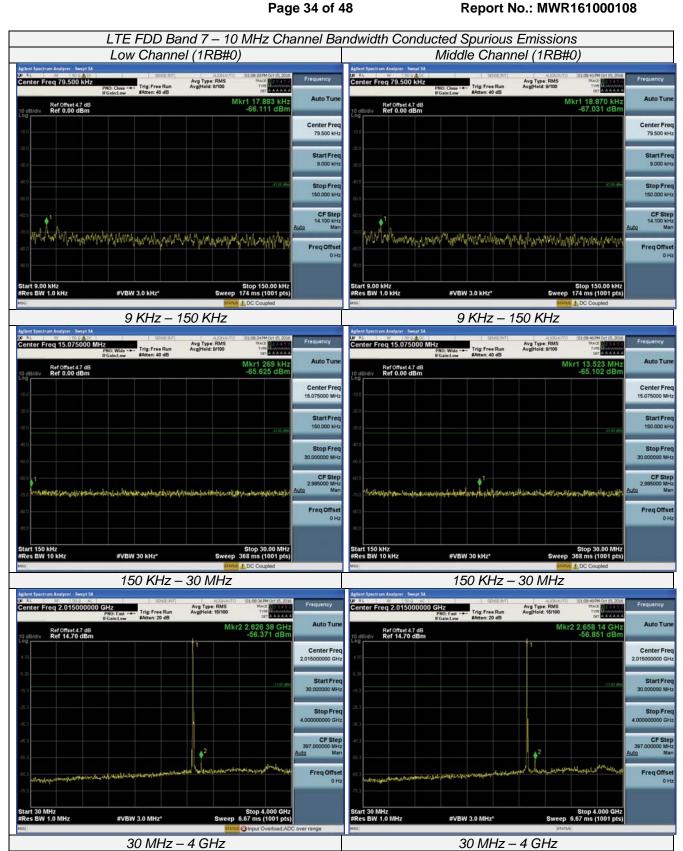
Working Frequency	Sub range (GHz)	RBW	VBW	Sweep time (s)
	0.000009~0.000015	1KHz	3KHz	Auto
LTE FDD Band 7	0.000015~0.03	10KHz	30KHz	Auto
LIE FDD Ballu I	0.03~4	1 MHz	3 MHz	Auto
	4~26	1 MHz	3 MHz	Auto

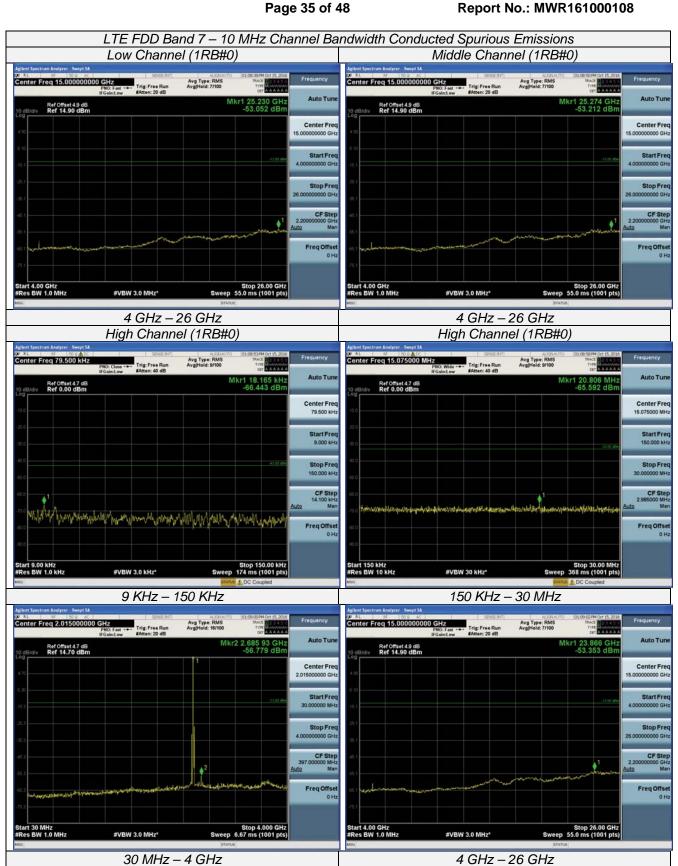
TEST RESULTS

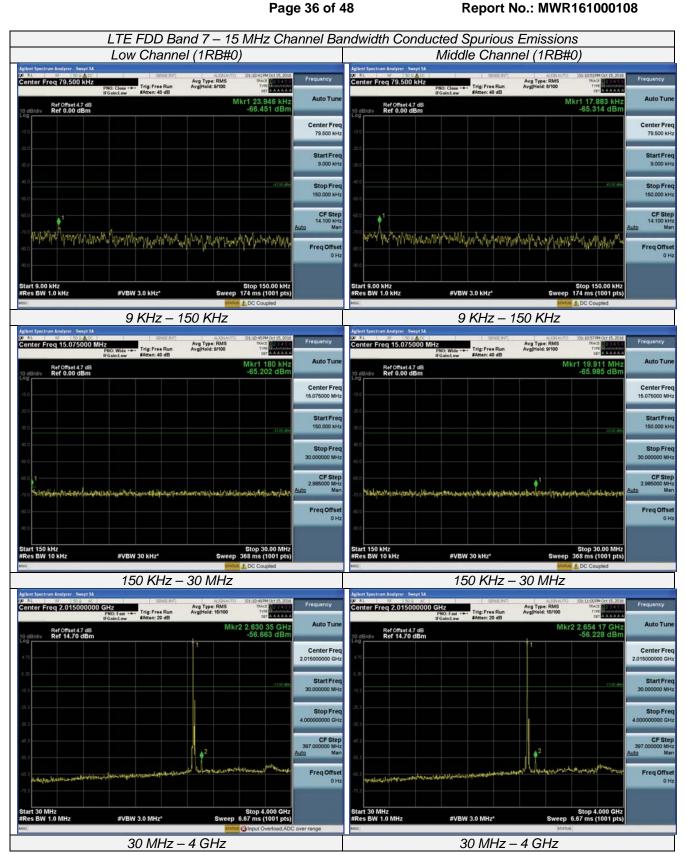
- 1. We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 7; recorded worst case for each Channel Bandwidth of LTE FDD Band 7.
- 2. We measured at SIM 1 as conducted burst average power higher at SIM 1;
- 3. We measured at both QPSK and 16QAM modulation, recorded worst case at QPSK modulation;

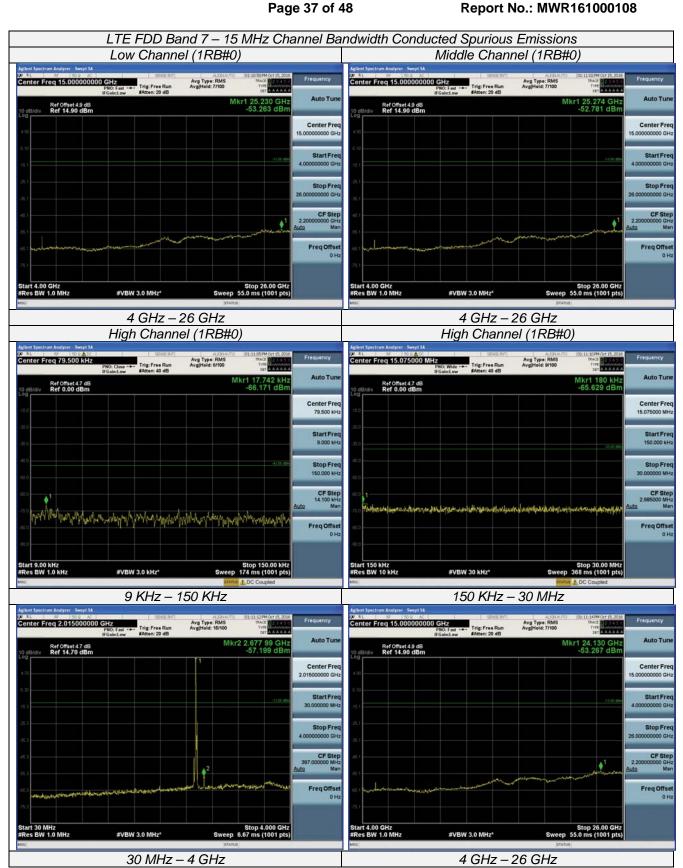


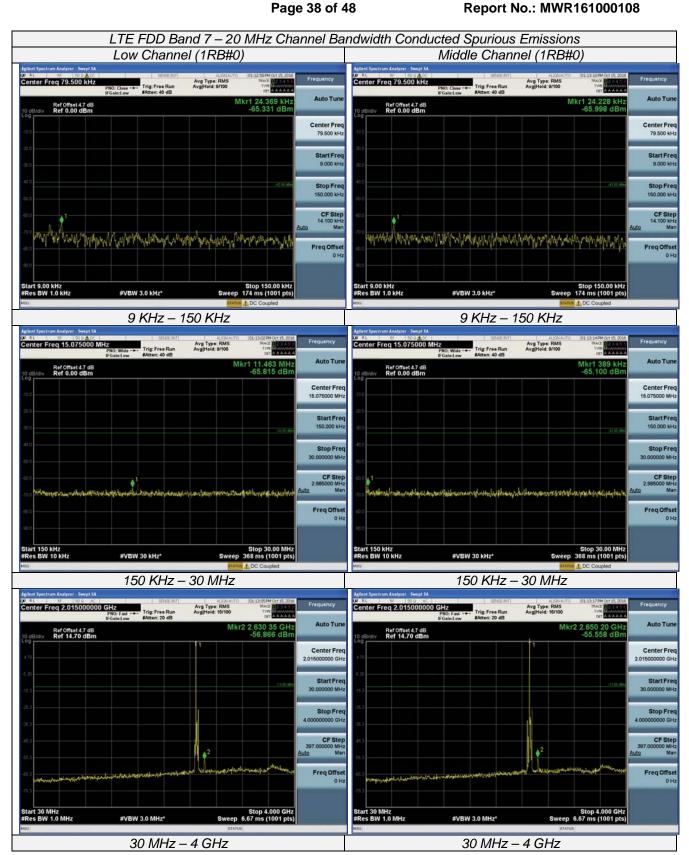


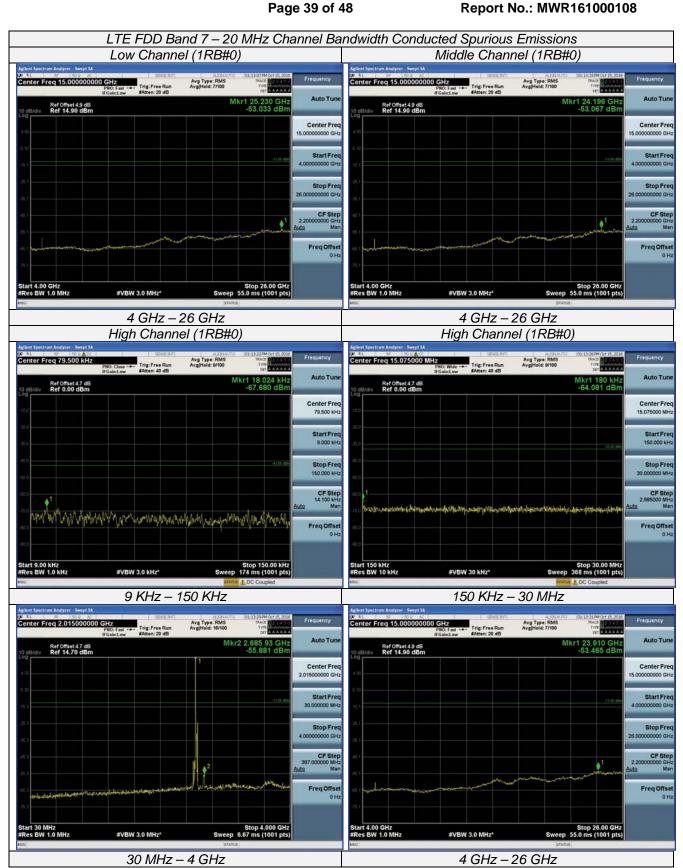










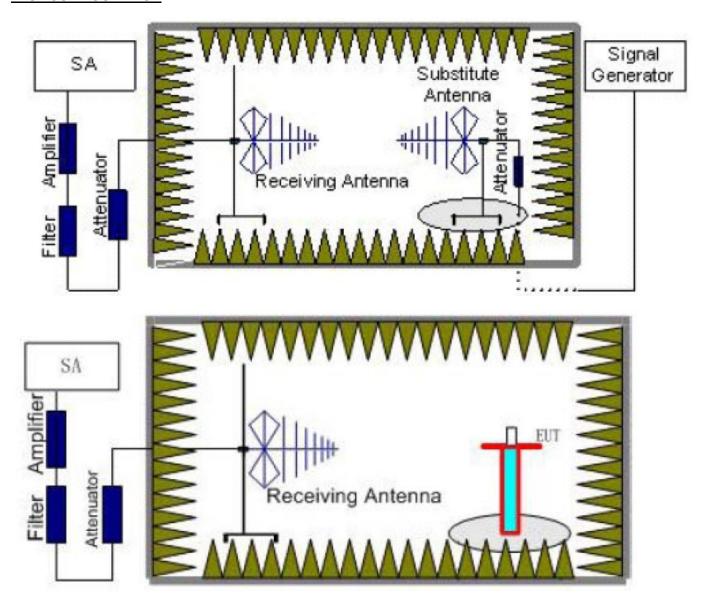


4.6. Radiated Spurious Emssion

LIMIT

According to §27.53 (h): For operations in the 1710–1755 MHz and 2110–2155 MHz bands, the power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) by at least 43 + 10 log10(P) dB.

TEST CONFIGURATION



TEST PROCEDURE

- 1. EUT was placed on a 1.50 meter high non-conductive stand at a 3 meter test distance from the receive antenna. A receiving antenna was placed on the antenna mast 3 meters from the EUT for emission measurements. The height of receiving antenna is 1.50 meter. Detected emissions were maximized at each frequency by rotating the EUT through 360° and adjusting the receiving antenna polarization. The radiated emission measurements of all transmit frequencies in three channels (High, Middle, Low) were measured with peak detector.
- 2. A log-periodic antenna or double-ridged waveguide horn antenna shall be substituted in place of the EUT. The log-periodic antenna will be driven by a signal generator and the level will be adjusted till the same power value on the spectrum analyzer or receiver. The level of the spurious emissions can be calculated through the level of the signal generator, cable loss, the gain of the substitution antenna and the reading of the spectrum analyzer or receiver.
- 3. The EUT is then put into continuously transmitting mode at its maximum power level during the test.Set Test Receiver or Spectrum RBW=1MHz,VBW=3MHz, And the maximum value of the receiver should be recorded as (P_r).

- 4. The EUT shall be replaced by a substitution antenna. In the chamber, an substitution antenna for the frequency band of interest is placed at the reference point of the chamber. An RF Signal source for the frequency band of interest is connected to the substitution antenna with a cable that has been constructed to not interfere with the radiation pattern of the antenna. A power (P_{Mea}) is applied to the input of the substitution antenna, and adjust the level of the signal generator output until the value of the receiver reach the previously recorded (P_r). The power of signal source (P_{Mea}) is recorded. The test should be performed by rotating the test item and adjusting the receiving antenna polarization.
- 5. A amplifier should be connected to the Signal Source output port. And the cable should be connect between the Amplifier and the Substitution Antenna. The cable loss (P_{cl}) ,the Substitution Antenna Gain (G_a) and the Amplifier Gain (P_{Ag}) should be recorded after test. The measurement results are obtained as described below: Power(EIRP)=P_{Mea}- P_{Ag} P_{cl} + G_a
- 6. This value is EIRP since the measurement is calibrated using an antenna of known gain (2.15 dBi) and known input power.
- 7. ERP can be calculated from EIRP by subtracting the gain of the dipole, ERP = EIRP -2.15dBi.
- 8. In order to make sure test results more clearly, we set frequency range and sweep time for difference frequency range as follows table:

Working Frequency	Subrange (GHz)	RBW	VBW	Sweep time (s)
	0.00009~0.15	1KHz	3KHz	30
	0.00015~0.03	10KHz	30KHz	10
	0.03~1	100KHz	300KHz	10
	1~2	1 MHz	3 MHz	2
	2~5	1 MHz	3 MHz	3
LTE FDD Band 7	5~8	1 MHz	3 MHz	3
	8~11	1 MHz	3 MHz	3
	11~14	1 MHz	3 MHz	3
	14~18	1 MHz	3 MHz	3
	18~20	1 MHz	3 MHz	2
	20~26	1 MHz	3 MHz	2

TEST LIMITS

According to 27.53(h) specify that the power of any emission outside of the authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least 43 + 10 log(P) dB. The specification that emissions shall be attenuated below the transmitter power (P) by at least 43 + 10 log (P) dB, translates in the relevant power range (1 to 0.001 W) to -13 dBm. At 1 W the specified minimum attenuation becomes 43 dB and relative to a 30 dBm (1 W) carrier becomes a limit of -13 dBm. At 0.001 W (0 dBm) the minimum attenuation is 13 dB, which again yields a limit of -13 dBm. In this way a translation of the specification from relative to absolute terms is carried out.

Frequency	Channel	Frequency Range	Verdict
	Low	9KHz -26GHz	PASS
LTE FDD Band 7	Middle	9KHz -26GHz	PASS
	High	9KHz -26GHz	PASS

Radiated Measurement:

Remark:

- 1. We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 7; recorded worst case for each Channel Bandwidth of LTE FDD Band 7.
- 2. $EIRP=P_{Mea}(dBm)-P_{cl}(dB)+G_{a}(dBi)$
- 3. We were not recorded other points as values lower than limits.
- 4. Margin = Limit EIRP
- 5. We measured at SIM 1 as conducted burst average power higher at SIM 1:

LTE FDD Band 7_Channel Bandwidth 5MHz_QPSK_ Low Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5005.00	-44.80	5.11	3.00	13.38	-36.53	-13.00	23.53	Н
7507.50	-50.08	6.02	3.00	13.98	-42.12	-13.00	29.12	Н
5005.00	-45.47	5.11	3.00	13.38	-37.20	-13.00	24.20	V
7507.50	-51.37	6.02	3.00	13.98	-43.41	-13.00	30.41	V

LTE FDD Band 7_Channel Bandwidth 5MHz_QPSK_ Middle Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5070.00	-42.32	5.11	3.00	13.38	-34.05	-13.00	21.05	Н
7605.00	-50.12	6.02	3.00	13.98	-42.16	-13.00	29.16	Н
5070.00	-45.88	5.11	3.00	13.38	-37.61	-13.00	24.61	V
7605.00	-52.10	6.02	3.00	13.98	-44.14	-13.00	31.14	V

LTE FDD Band 7 Channel Bandwidth 5MHz QPSK High Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5135.00	-45.01	5.11	3.00	13.38	-36.38	-13.00	23.38	Н
7702.50	-48.63	6.02	3.00	13.98	-43.36	-13.00	30.36	Н
5135.00	-52.44	5.11	3.00	13.38	-37.61	-13.00	24.61	V
7702.50	-54.27	6.02	3.00	13.98	-44.82	-13.00	31.82	V

LTE FDD Band 7_Channel Bandwidth 10MHz_QPSK_ Low Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5010.00	-47.40	5.11	3.00	13.38	-39.13	-13.00	26.13	Н
7515.00	-51.64	6.02	3.00	13.98	-43.68	-13.00	30.68	Н
5010.00	-46.38	5.11	3.00	13.38	-38.11	-13.00	25.11	V
7515.00	-53.73	6.02	3.00	13.98	-45.77	-13.00	32.77	V

LTE FDD Band 7 Channel Bandwidth 10MHz QPSK Middle Channel

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Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5070.00	-46.21	5.11	3.00	13.38	-37.94	-13.00	24.94	Н
7605.00	-50.95	6.02	3.00	13.98	-42.99	-13.00	29.99	Н
5070.00	-48.95	5.11	3.00	13.38	-40.68	-13.00	27.68	V
7605.00	-51.21	6.02	3.00	13.98	-43.25	-13.00	30.25	V

LTE FDD Band 7 Channel Bandwidth 10MHz QPSK High Channel

	<u> </u>			<u> </u>	•			
Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5130.00	-45.49	5.11	3.00	13.38	-37.22	-13.00	24.22	Н
7695.00	-50.69	6.02	3.00	13.98	-42.73	-13.00	29.73	Н
5130.00	-48.97	5.11	3.00	13.38	-40.70	-13.00	27.70	V
7695.00	-52.29	6.02	3.00	13.98	-44.33	-13.00	31.33	V

LTE FDD Band 7_Channel Bandwidth 15MHz_QPSK_ Low Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5015.00	-46.49	5.11	3.00	13.38	-38.22	-13.00	25.22	Н
7522.50	-49.12	6.02	3.00	13.98	-41.16	-13.00	28.16	Н
5015.00	-48.52	5.11	3.00	13.38	-40.25	-13.00	27.25	V
7522.50	-51.37	6.02	3.00	13.98	-43.41	-13.00	30.41	V

LTE FDD Band 7_Channel Bandwidth 15MHz_QPSK_ Middle Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5070.00	-45.68	5.11	3.00	13.38	-37.41	-13.00	24.41	Н
7605.00	-51.95	6.02	3.00	13.98	-43.99	-13.00	30.99	Н
5070.00	-46.30	5.11	3.00	13.38	-38.03	-13.00	25.03	V
7605.00	-53.98	6.02	3.00	13.98	-46.02	-13.00	33.02	V

LTE FDD Band 7_Channel Bandwidth 15MHz_QPSK_ High Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5125.00	-46.01	5.11	3.00	13.38	-37.74	-13.00	24.74	Н
7687.50	-52.16	6.02	3.00	13.98	-44.20	-13.00	31.20	Н
5125.00	-47.06	5.11	3.00	13.38	-38.79	-13.00	25.79	V
7687.50	-53.98	6.02	3.00	13.98	-46.02	-13.00	33.02	V

LTE FDD Band 7_Channel Bandwidth 20MHz_QPSK_ Low Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5020.00	-46.56	5.11	3.00	13.38	-38.29	-13.00	25.29	Н
7530.00	-53.20	6.02	3.00	13.98	-45.24	-13.00	32.24	Н
5020.00	-49.27	5.11	3.00	13.38	-41.00	-13.00	28.00	V
7530.00	-55.24	6.02	3.00	13.98	-47.28	-13.00	34.28	V

LTE FDD Band 7 Channel Bandwidth 20MHz QPSK Middle Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5070.00	-48.52	5.11	3.00	13.38	-40.25	-13.00	27.25	Н
7605.00	-51.52	6.02	3.00	13.98	-43.56	-13.00	30.56	Н
5070.00	-48.98	5.11	3.00	13.38	-40.71	-13.00	27.71	V
7605.00	-52.22	6.02	3.00	13.98	-44.26	-13.00	31.26	V

LTE FDD 7_Channel Bandwidth 20MHz_QPSK_ High Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5120.00	-47.60	5.11	3.00	13.38	-39.33	-13.00	26.33	Н
7680.00	-52.12	6.02	3.00	13.98	-44.16	-13.00	31.16	Н
5120.00	-48.52	5.11	3.00	13.38	-40.25	-13.00	27.25	V
7680.00	-53.98	6.02	3.00	13.98	-46.02	-13.00	33.02	V

LTE FDD Band 7 Channel Bandwidth 5MHz 16QAM Low Channel

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Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5005.00	-46.50	5.11	3.00	13.38	-38.23	-13.00	25.23	Н
7507.50	-50.76	6.02	3.00	13.98	-42.80	-13.00	29.80	Н
5005.00	-48.55	5.11	3.00	13.38	-40.28	-13.00	27.28	V
7507.50	-53.17	6.02	3.00	13.98	-45.21	-13.00	32.21	V

LTE FDD Band 7_Channel Bandwidth 5MHz_16QAM _ Middle Channel

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Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization				
5070.00	-45.12	5.11	3.00	13.38	-36.85	-13.00	23.85	Н				
7605.00	-48.80	6.02	3.00	13.98	-40.84	-13.00	27.84	Н				
5070.00	-46.90	5.11	3.00	13.38	-38.63	-13.00	25.63	V				
7605.00	-52.16	6.02	3.00	13.98	-44.20	-13.00	31.20	V				

LTE FDD Band 7_Channel Bandwidth 5MHz_16QAM _ High Channel

		=			• • • • • • • • • • • • • • • • • • • •			
Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5135.00	-46.47	5.11	3.00	13.38	-38.20	-13.00	25.20	Н
7702.50	-49.80	6.02	3.00	13.98	-41.84	-13.00	28.84	Н
5135.00	-49.81	5.11	3.00	13.38	-41.54	-13.00	28.54	V
7702.50	-51.86	6.02	3.00	13.98	-43.90	-13.00	30.90	V

LTE FDD Band 7_Channel Bandwidth 10MHz_16QAM Low Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5010.00	-37.69	5.11	3.00	13.38	-29.42	-13.00	16.42	Н
7515.00	-44.18	6.02	3.00	13.98	-36.22	-13.00	23.22	Н
5010.00	-40.16	5.11	3.00	13.38	-31.89	-13.00	18.89	V
7515.00	-45.78	6.02	3.00	13.98	-37.82	-13.00	24.82	V

LTE FDD Band 7 Channel Bandwidth 10MHz 16QAM Middle Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5070.00	-46.43	5.11	3.00	13.38	-38.16	-13.00	25.16	Н
7605.00	-50.99	6.02	3.00	13.98	-43.03	-13.00	30.03	Н
5070.00	-48.46	5.11	3.00	13.38	-40.19	-13.00	27.19	V
7605.00	-52.15	6.02	3.00	13.98	-44.19	-13.00	31.19	V

LTE FDD Band 7 Channel Bandwidth 10MHz 16QAM High Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5130.00	-48.27	5.11	3.00	13.38	-40.00	-13.00	27.00	Н
7695.00	-54.32	6.02	3.00	13.98	-46.36	-13.00	33.36	Н
5130.00	-49.66	5.11	3.00	13.38	-41.39	-13.00	28.39	V
7695.00	-52.72	6.02	3.00	13.98	-44.76	-13.00	31.76	V

LTE FDD Band 4_Channel Bandwidth 15MHz_16QAM _ Low Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5015.00	-49.24	5.11	3.00	13.38	-40.97	-13.00	27.97	Н
7522.50	-51.23	6.02	3.00	13.98	-43.27	-13.00	30.27	Н
5015.00	-50.47	5.11	3.00	13.38	-42.20	-13.00	29.20	V
7522.50	-52.83	6.02	3.00	13.98	-44.87	-13.00	31.87	V

LTE FDD Band 7_Channel Bandwidth 15MHz_16QAM _ Middle Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5070.00	-47.04	5.11	3.00	13.38	-38.77	-13.00	25.77	Н
7605.00	-51.16	6.02	3.00	13.98	-43.20	-13.00	30.20	Н
5070.00	-49.47	5.11	3.00	13.38	-41.20	-13.00	28.20	V
7605.00	-52.31	6.02	3.00	13.98	-44.35	-13.00	31.35	V

LTE FDD Band 7_Channel Bandwidth 15MHz_16QAM _ High Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5125.00	-49.44	5.11	3.00	13.38	-41.17	-13.00	28.17	Н
7687.50	-51.91	6.02	3.00	13.98	-43.95	-13.00	30.95	Н
5125.00	-50.47	5.11	3.00	13.38	-42.20	-13.00	29.20	V
7687.50	-54.49	6.02	3.00	13.98	-46.53	-13.00	33.53	V

LTE FDD Band 7_Channel Bandwidth 20MHz_16QAM _ Low Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5020.00	-50.47	5.11	3.00	13.38	-42.20	-13.00	29.20	Н
7530.00	-55.45	6.02	3.00	13.98	-47.49	-13.00	34.49	Н
5020.00	-49.50	5.11	3.00	13.38	-41.23	-13.00	28.23	V
7530.00	-55.88	6.02	3.00	13.98	-47.92	-13.00	34.92	V

LTE FDD Band 7_Channel Bandwidth 20MHz_16QAM _ Middle Channel

Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5070.00	-48.27	5.11	3.00	13.38	-40.00	-13.00	27.00	Н
7605.00	-51.00	6.02	3.00	13.98	-43.04	-13.00	30.04	Н
5070.00	-46.93	5.11	3.00	13.38	-38.66	-13.00	25.66	V
7605.00	-52.17	6.02	3.00	13.98	-44.21	-13.00	31.21	V

LTE FDD Band 7_Channel Bandwidth 20MHz_16QAM _ High Channel

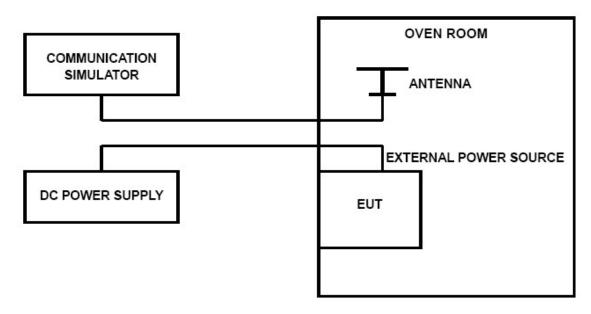
Frequency (MHz)	P _{Mea} (dBm)	P _{cl} (dB)	Diatance	G _a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
5120.00	-47.17	5.11	3.00	13.38	-38.90	-13.00	25.90	Н
7680.00	-52.17	6.02	3.00	13.98	-44.21	-13.00	31.21	Н
5120.00	-49.39	5.11	3.00	13.38	-41.12	-13.00	28.12	V
7680.00	-54.35	6.02	3.00	13.98	-46.39	-13.00	33.39	V

4.7. Frequency Stability

LIMIT

According to §27.54, §2.1055 requirement, the frequency stability shall be sufficient to ensure that the fundamental emissions stay within the authorized bands of operation and should not exceed 2.5ppm.

TEST CONFIGURATION



TEST PROCEDURE

The EUT was setup according to EIA/TIA 603D

Frequency Stability Under Temperature Variations:

In order to measure the carrier frequency under the condition of AFC lock, it is necessary to make measurements with the EUT in a "call mode". This is accomplished with the use of R&S CMW500 DIGITAL RADIO COMMUNICATION TESTER.

- 1. Measure the carrier frequency at room temperature.
- 2. Subject the EUT to overnight soak at -30 °C.
- 3. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on middle channel for LTE band 4, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
- 4. Repeat the above measurements at 10° C increments from -30° C to $+50^{\circ}$ C. Allow at least 1.5 hours at each temperature, unpowered, before making measurements.
- 5. Re-measure carrier frequency at room temperature with nominal voltage. Vary supply voltage from minimum voltage to maximum voltage, in 0.1Volt increments re-measuring carrier frequency at each voltage. Pause at nominal voltage for 1.5 hours unpowered, to allow any self-heating to stabilize, before continuing.
- 6. Subject the EUT to overnight soak at $+50^{\circ}$ C.
- 7. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on the centre channel, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
- 8. Repeat the above measurements at 10 $^{\circ}$ C increments from +50 $^{\circ}$ C to -30 $^{\circ}$ C. Allow at least 1.5 hours at each temperature, unpowered, before making measurements
- 9. At all temperature levels hold the temperature to +/- 0.5° C during the measurement procedure.

Frequency Stability Under Voltage Variations:

Set chamber temperature to 20° C. Use a variable AC power supply / DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency.

Reduce the input voltage to specify extreme voltage variation (±15%) and endpoint, record the maximum frequency change.

TEST RESULTS

Remark:

- 1. We tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 7; recorded worst case.
- 2. We measured at SIM 1 as conducted burst average power higher at SIM 1;

LTE Band 7, 5 MHz bandwidth , QPSK (worst case of all bandwidths)

LTE FDD Band 7							
DC Power	Temperature (°C)	Frequency error(Hz)	Frequency error(ppm)	Limit (ppm)	Verdict		
3.40	20	8.68	0.003	2.50	PASS		
3.80	20	-8.12	0.003	2.50	PASS		
4.20	20	4.85	0.002	2.50	PASS		
3.80	-30	5.36	0.002	2.50	PASS		
3.80	-20	-8.16	0.003	2.50	PASS		
3.80	-10	-6.35	0.003	2.50	PASS		
3.80	0	5.12	0.002	2.50	PASS		
3.80	10	-3.78	0.001	2.50	PASS		
3.80	20	-5.89	0.002	2.50	PASS		
3.80	30	4.89	0.002	2.50	PASS		
3.80	40	-5.74	0.002	2.50	PASS		
3.80	50	6.75	0.003	2.50	PASS		

LTE Band 7, 5 MHz bandwidth, 16QAM (worst case of all bandwidths)

LTE FDD Band 7							
DC Power	Temperature (°C)	Frequency error(Hz)	Frequency error(ppm)	Limit (ppm)	Verdict		
3.40	20	8.26	0.003	2.50	PASS		
3.80	20	5.14	0.002	2.50	PASS		
4.20	20	-3.65	0.001	2.50	PASS		
3.80	-30	3.78	0.001	2.50	PASS		
3.80	-20	6.87	0.003	2.50	PASS		
3.80	-10	-6.47	0.003	2.50	PASS		
3.80	0	-4.71	0.002	2.50	PASS		
3.80	10	6.12	0.002	2.50	PASS		
3.80	20	-3.16	0.001	2.50	PASS		
3.80	30	-2.79	0.001	2.50	PASS		
3.80	40	8.74	0.003	2.50	PASS		
3.80	50	-5.16	0.002	2.50	PASS		

Report No.: MWR161000108

5. Test Setup Photos of the EUT

Please refer to separated files for Test Setup Photos of the EUT.

6. External Photos of the EUT

Please refer to separated files for External Photos of the EUT.

7. Internal Photos of the EUT

Please refer to separated files for Internal Photos of the EUT.

